LUIS CASTAÑER

UNDERSTANDING

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**PRINCIPLES AND APPLICATIONS** 



WILEY

# UNDERSTANDING MEMS PRINCIPLES AND APPLICATIONS

#### Luis Castañer

Department of Electronic Engineering Universitat Politécnica de Cataluña, Spain



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### **UNDERSTANDING MEMS**

To my wife Pamen, daughters Maya and Olga, grandsons Teo, Raul and Marc-Eric and granddaughter Claudia

#### **Preface**

The field of microelectromechanical systems (MEMS) has greatly expanded in recent years since Richard Feyman's speech – 'there is plenty of room at the bottom' – opened the minds of researchers and companies to the possibility of exploring the potential of microstructures of minute dimensions.

The need for skilled professionals has steadily grown as businesses and research labs engage in challenging projects. Students are motivated because they are aware that they have, in their phones, watches or tablets, accelerometers, compasses and sensors and useful applications relying on them. Students see in the MEMS field, job opportunities and exciting career prospects.

Ultimately those devices have to work together with front-end electronics and digital processing to interface with the user. Students in electrical engineering and computer science departments in universities around the world are probably the most exposed to the field. Simultaneously, engineers and professionals working in the electronics and semiconductor industry face the challenge of integrating MEMS devices into chips, systems on chips or, broadly speaking, into electronic systems. The added value of those devices enables the expansion of high tech businesses.

In my experience of teaching MEMS in an electronic engineering department to engineering students from many countries I have faced the difficulty of selecting material for one-semester course and having to decide on the depth and breadth of the subjects covered.

The field is inherently multidisciplinary, and if the basics are not sufficiently covered, students will not achieve the intellectual satisfaction of a full understanding. However, if the coverage is too complex it cannot be extended to the various fundamental domains underlying the field. Solving problems is an important part of the learning process as it allows for concepts to be reviewed.

Those are the reasons why I have chosen to approach the subject using analytical solutions as far as possible, but with the help of two software tools: one very popular among science and engineering students, Matlab; and the other, very popular among electrical engineering students, PSpice. I have used Matlab to solve ordinary differential equations subject to boundary or initial conditions, applied to mechanical, electromechanical, electrokinetic and thermal problems. This allows numerical results to be found quickly which can then be discussed and put into context.

I have used PSpice to solve Laplace transforms of transfer functions and to solve electrical equivalent circuits of lumped thermal problems. Apart from the clarity of analytical solutions, this approach places the subject of MEMS in the same tool environment as other subjects the

xiv Preface

student will already have taken. Commonality of tools is important at this level of the learning process, because it means that students do not have to spend a significant amount of time learning how to use new software.

The book includes 52 worked examples in the text and 100 solved problems in the appendices, organized by chapters. In my view this allows this textbook to be used not only as support material for a conventional course but also as a self-study resource for distance learning. I am very greatful to faculty colleagues, researchers and students with whom I have interacted all these years that have taken me to complete this book.

Luis Castañer April 2015 Barcelona, Spain

## About the Companion Website

This book is accompanied by a companion website:

www.wiley.com/go/castaner/understandingmems

The website includes:

- Matlab
- PSpice codes
- Chapter viewgraphs

### Contents

Pref	face	xiii
Abo	ut the Companion Website	xv
1	Scaling of Forces	1
1.1	Scaling of Forces Model	1
1.2	Weight	
	1.2.1 Example: MEMS Accelerometer	2 2
1.3	Elastic Force	3
	1.3.1 Example: AFM Cantilever	4
1.4	Electrostatic Force	4
	1.4.1 Example: MEMS RF Switch	6
1.5	Capillary Force	6
	1.5.1 Example: Wet Etching Force	8
1.6	Piezoelectric Force	8
	1.6.1 Example: Force in Film Embossing	9
1.7	Magnetic Force	10
	1.7.1 Example: Compass Magnetometer	10
1.8	Dielectrophoretic Force	11
	1.8.1 Example: Nanoparticle in a Spherical Symmetry Electric Field	12
1.9	Summary	13
	Problems	13
2	Elasticity	15
2.1	Stress	15
2.2	Strain	18
2.3	Stress-strain Relationship	20
	2.3.1 Example: Plane Stress	21
2.4	Strain-stress Relationship in Anisotropic Materials	22
2.5	Miller Indices	23
	2.5.1 Example: Miller Indices of Typical Planes	24
2.6	Angles of Crystallographic Planes	25
	2.6.1 Example	25
2.7	Compliance and Stiffness Matrices for Single-Crystal Silicon	26
	2.7.1 Example: Young's Modulus and Poisson Ratio for (100) Silicon	27

viii

2.8	Orthogonal Transformation	29
2.9	Transformation of the Stress State	31
	2.9.1 Example: Rotation of the Stress State	31
	2.9.2 Example: Matrix Notation for the Rotation of the Stress State	32
2.10	Orthogonal Transformation of the Stiffness Matrix	32
2.10	2.10.1 Example: $C_{11}$ Coefficient in Rotated Axes	33
	2.10.2 Example: Young's Modulus and Poisson Ratio in the (111) Direction	34
2.11		36
2.11	Elastic Properties of Selected MEMS Materials	36
	Problems	30
3	Bending of Microstructures	37
3.1	Static Equilibrium	37
3.2	Free Body Diagram	38
3.3	Neutral Plane and Curvature	39
3.4	Pure Bending	40
	3.4.1 Example: Neutral Plane for a Rectangular Cross-section	41
	3.4.2 Example: Cantilever with Point Force at the Tip	42
3.5	Moment of Inertia and Bending Moment	43
	3.5.1 Example: Moment of Inertia of a Rectangular Cross-section	43
3.6	Beam Equation	44
3.7	End-loaded Cantilever	45
3.8	Equivalent Stiffness	47
3.9	Beam Equation for Point Load and Distributed Load	48
3.10	Castigliano's Second Theorem	48
5.10	3.10.1 Strain Energy in an Elastic Body Subject to Pure Bending	50
3.11	Flexures	51
5.11	3.11.1 Fixed-fixed Flexure	51
	3.11.2 Example: Comparison of Stiffness Constants	53
	3.11.3 Example: Folded Flexure	53
3.12	Rectangular Membrane	54
		55
3.13	Simplified Model for a Rectangular Membrane Under Pressure	
2 14	3.13.1 Example: Thin Membrane Subject to Pressure	57
3.14	Edge-clamped Circular Membrane	58
	Problems	60
4	Piezoresistance and Piezoelectricity	65
4.1	Electrical Resistance	65
	4.1.1 Example: Resistance Value	66
4.2	One-dimensional Piezoresistance Model	67
	4.2.1 Example: Gauge Factors	68
4.3	Piezoresistance in Anisotropic Materials	69
4.4	Orthogonal Transformation of Ohm's Law	70
4.5	Piezoresistance Coefficients Transformation	71
	4.5.1 Example: Calculation of Rotated Piezoresistive Components $\pi'_{11}$ ,	
	$\pi'_{12}$ and $\pi'_{16}$ for unit axes X' [110], Y' [ $\bar{1}$ 10] and Z' [001]	72
	4.5.2 Analytical Expressions for Some Rotated Piezoresistive Components	74

Contents

4.6	Two-dimensional Piezoresistors	74
	4.6.1 Example: Accelerometer with Cantilever and Piezoresistive Sensing	76
4.7	Pressure Sensing with Rectangular Membranes	79
	4.7.1 Example: Single-resistor Pressure Sensor	82
	4.7.2 Example: Pressure Sensors Comparison	85
4.8	Piezoelectricity	86
	4.8.1 Relevant Data for Some Piezoelectric Materials	88
	4.8.2 Example: Piezoelectric Generator	89
	Problems	91
5	Electrostatic Driving and Sensing	93
5.1	Energy and Co-energy	93
5.2	Voltage Drive	97
5.3	Pull-in Voltage	97
	5.3.1 Example: Forces in a Parallel-plate Actuator	99
5.4	Electrostatic Pressure	101
5.5	Contact Resistance in Parallel-plate Switches	101
5.6	Hold-down Voltage	101
	5.6.1 Example: Calculation of Hold-down Voltage	102
5.7	Dynamic Response of Pull-in-based Actuators	102
	5.7.1 Example: Switching Transient	103
5.8	Charge Drive	105
5.9	Extending the Stable Range	105
5.10	Lateral Electrostatic Force	106
5.11	Comb Actuators	106
5.12	Capacitive Accelerometer	108
5.13	Differential Capacitive Sensing	108
5.14	Torsional Actuator	110
	Problems	111
6	Resonators	115
6.1	Free Vibration: Lumped-element Model	115
6.2	Damped Vibration	116
6.3	Forced Vibration	117
	6.3.1 Example: Vibration Amplitude as a Function of the Damping Factor	120
6.4	Small Signal Equivalent Circuit of Resonators	121
	6.4.1 Example: Series and Parallel Resonances	125
	6.4.2 Example: Spring Softening	125
6.5	Rayleigh–Ritz Method	126
	6.5.1 Example: Vibration of a Cantilever	128
	6.5.2 Example: Gravimetric Chemical Sensor	129
6.6	Resonant Gyroscope	130 133
6.7	Tuning Fork Gyroscope  6.7.1 Example: Calculation of Sansitivity in a Tuning Fork Gyroscope	134
	6.7.1 Example: Calculation of Sensitivity in a Tuning Fork Gyroscope Problems	135
	1 TOULEHIS	100

x Contents

7	Microfluidics and Electrokinetics	137
7.1	Viscous Flow	137
7.2	Flow in a Cylindrical Pipe	140
_ = =	7.2.1 Example: Pressure Gradient Required to Sustain a Flow	141
7.3	Electrical Double Layer	142
View 100	7.3.1 Example: Debye Length and Surface Charge	144
7.4	Electro-osmotic Flow	144
7.5	Electrowetting	146
	7.5.1 Example: Droplet Change by Electrowetting	148
	7.5.2 Example: Full Substrate Contacts	149
7.6	Electrowetting Dynamics	151
	7.6.1 Example: Contact-angle Dynamics	153
7.7	Dielectrophoresis	153
	7.7.1 Electric Potential Created by a Constant Electric Field	154
	7.7.2 Potential Created by an Electrical Dipole	155
	7.7.3 Superposition	156
	Problems	157
8	Thermal Devices	159
8.1	Steady-state Heat Equation	159
8.2	Thermal Resistance	161
	8.2.1 Example: Temperature Profile in a Heated Wire	162
	8.2.2 Example: Resistor Suspended in a Bridge	165
8.3	Platinum Resistors	166
8.4	Flow Measurement Based on Thermal Sensors	166
	8.4.1 Example: Micromachined Flow Sensor	169
8.5	Dynamic Thermal Equivalent Circuit	171
8.6	Thermally Actuated Bimorph	172
	8.6.1 Example: Bimorph Actuator	174
8.7	Thermocouples and Thermopiles	175
	8.7.1 Example: IR Detector	175
	Problems	176
9	Fabrication	181
9.1	Introduction	181
9.2	Photolithography	182
9.3	Patterning	183
9.4	Lift-off	184
9.5	Bulk Micromachining	184
	9.5.1 Example: Angle of Walls in Silicon (100) Etching	185
9.6	Silicon Etch Stop When Using Alkaline Solutions	186
	9.6.1 Example: Boron drive-in at 1050°C	186
9.7	Surface Micromachining	186
	9.7.1 Example: Cantilever Fabrication by Surface Micromachining	187
9.8	Dry Etching	188

Contents

9.9	CMOS-compatible MEMS Processing	188
	9.9.1 Example: Bimorph Actuator Compatible with CMOS Process	189
9.10	Wafer Bonding	190
9.11	PolyMUMPs Foundry Process	190
	9.11.1 Example: PolyMUMPs Cantilever for a Fabry–Perot Pressure	
	Sensor	191
	Problems	192
APPI	ENDICES	195
A	Chapter 1 Solutions	197
В	Chapter 2 Solutions	207
C	Chapter 3 Solutions	221
D	Chapter 4 Solutions	239
E	Chapter 5 Solutions	249
F	Chapter 6 Solutions	267
G	Chapter 7 Solutions	277
H	Chapter 8 Solutions	285
I	Chapter 9 Solutions	299
Refer	ences	307
Index		311